

A structural differentiation of quaternary copper argyrodites: Structure – property relations of high temperature ion conductors

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Dedicated to Professor Dr. Hans-Jörg Deiseroth on the occasion of his 60th birthday

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Abstract. The crystal structures of 12 argyrodite type copper compounds with the general formula $\text{Cu}_{(12-n)}\text{B}^{n+}\text{Q}^{2-}_{6-y}\text{X}_y$ ($\text{B} = \text{P, As, Si, Ge}$; $\text{Q} = \text{S, Se}$; $\text{X} = \text{Cl, Br, I}$) were refined. The positions of the copper atoms were refined by using a non-harmonic approach. All polymorphic argyrodites were investigated in their cubic high temperature modification crystallizing in spacegroup $F\bar{4}3m$ (No. 216). A comprehensible way to describe the complex structures was developed based on a topological description of the rigid anion- and B -cation substructure as an arrangement of Frank-Kasper polyhedra. An analysis of the joint probability density function and of the one particle potentials for the copper atoms was performed to get a detailed insight in the copper distribution in these argyrodites. They can be divided into four types based on their different distribution of copper.

This classification corresponds to the physical properties of the argyrodites, especially to their ionic conductivities, which show a significant dependence on the composition.

Introduction

The argyrodites were declared as a structure family by Hahn, Schulze and Sechser (1965), and Kuhs, Nitsche and Scheunemann (1978a; 1979), and can be derived from the mineral Ag_8GeS_6 called Argyrodite (Goldschmidt, 1909; Palache, Berman and Fondel, 1944). The ternary members of the structure family have the general formula $\text{A}^{m+}_{(12-n/m)}\text{B}^{n+}\text{Q}^{2-}_6$. A^{m+} are restricted to Cu^+ , Ag^+ , Cd^{2+} (Krebs and Mandt, 1972; Susa and Steinfink, 1971) and Hg^{2+} (Gulay, Olekseyuk and Parasyuk, 2002) but the B -cation can be substituted by tetravalent Ti and pentavalent Nb or Ta (e.g.

in $\text{Ag}_{(12-n)}\text{B}^{n+}\text{Q}_6$, $\text{Q} = \text{S, Se}$) (Onoda, Wada, Hiroaki and Tansho, 1998; Wada, 1992; Wada, Sato, Onoda, Adams, Tansho and Ishii, 2002) and most of the group 13 to group 15 elements of the periodic table (trivalent Al and Ga (Gaudin, Deiseroth and Zaiss, 2001; Tansho, Wada, Ishii and Onoda, 1996) tetravalent Si, Ge and Sn (Matje and Schön, 1980) and pentavalent P and As. Sulfur can be substituted by selenium or tellurium ($\text{Q} = \text{S, Se, Te}$).

Intense research on the ternary argyrodites was performed in the last three decades because of their interesting physical properties, especially ion conductivity (e.g. $\text{Ag}_{6.69}\text{GeSe}_5\text{I}_{0.69}$: Belin, Aldon, Zerouale, Belin and Ribes, 2001) and photovoltaic and illumination effects (Batirov, Fridkin, Nitsche and Verkhovskaya, 1982).

The high ionic conductivity results from order-disorder phenomena in the substructure of the A -cations. Contrary, the substructure of the B -cation and the anions is rigid. However, one chalcogen atom can be substituted by a halogen atom resulting in compositions like $\text{A}^{m+}_{(12-n/m)}\text{B}^{n+}\text{Q}^{2-}_{6-y}\text{X}_y$ ($\text{X} = \text{Cl, Br, I}$). Starting from the disordered high-temperature modification, which is the aristo-type of the structure family, several partially or fully ordered hetto-types were found. The aristo-type often shows high ionic conductivity and is therefore of particular interest for electrochemical devices like batteries and sensors. $\text{Cu}_6\text{PS}_5\text{I}$ is the best studied quaternary copper argyrodite. Besides high ionic conductivity this material exhibits ferroelastic and nonlinear optical properties (Kuhs et al., 1979; Studenyak, Stefanovich, Kranjcec, Desnica, Azhniuk, Kovacs and Panko, 1997). The determination of the electrical properties of $\text{Cu}_7\text{GeS}_5\text{I}$ and the comparison of them with other quaternary silver and copper argyrodites like $\text{Cu}_6\text{PS}_5\text{I}$ and $\text{Ag}_7\text{GeS}_5\text{I}$ by Studenyak, Kranjcec, Kovac, Desnica-Frankovic, Molnar, Panko and Slivka (2002), proved an enhancement of conductivity after heterovalent substitution of P with Ge and the corresponding change in the content of monovalent cations. The crystal structures of the quaternary copper argyrodites have been scarcely studied despite their promising properties for electrochemical devices. Herein we report the determination of the crystal structures of 12 quaternary copper argyrodites and the analysis of them with respect to ionic conductivity.

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Table 1. Details of the preparation of the quaternary copper argyrodites.

Compound	Annealing temperature in K	Annealing time in d
Cu ₆ PS ₅ Cl	923	41
Cu ₆ PS ₅ Br	923	41
Cu ₆ PS ₅ I	1023	37
Cu ₆ AsS ₅ Br	853	62
Cu ₆ AsS ₅ I	873	30
Cu _{7.82} SiS _{5.82} Br _{0.18}	1193	19
Cu ₇ SiS ₅ I	1173	19
Cu _{7.49} SiS _{5.49} I _{0.51}	1193	19
Cu _{7.44} SiSe _{5.44} I _{0.56}	1193	19
Cu _{7.75} GeS _{5.75} Br _{0.25}	1153	23
Cu ₇ GeS ₅ I	1123	25
Cu _{7.52} GeSe _{5.52} I _{0.48}	960	25

Experimental

Preparation

The argyrodites were prepared by the reaction of stoichiometric mixtures of the respective elements in evacuated silica ampoules. The starting materials were heated to 1223 K in case of Cu₆PS₅X ($X = \text{Cl, Br, I}$), 1273 K in case of Cu_{8- x} BQ_{6- x} X _{x} ($B = \text{Si, Ge}$; $Q = \text{S, Se}$; $X = \text{Br, I}$) and Cu₆AsS₅X ($X = \text{Br, I}$), and 1373 K for Cu₇SiS_{6- x} I _{x} . After grinding the argyrodites were annealed at temperatures between 923 K and 1193 K for at least 19 days.

Details concerning the composition of the materials, the annealing temperatures and the annealing times are summarized in Table 1.

X-ray powder diffraction

All materials were investigated by X-ray powder diffraction in order to determine the resulting phases and to compare the results with those reported by Kuhs et al. (1979). The compositions calculated from single crystal X-ray data were taken to prepare phase pure samples of the respective materials. The purity was checked using a Stoe STADIP powder diffractometer or a Siemens D5000 powder diffractometer, both equipped with a linear 5° PSD (CuK α_1 radiation, $\lambda = 1.54051 \text{ \AA}$, germanium monochromator). Table 2 summarizes the results from the phase analysis.

The comparison of the different compositions for the argyrodites leads to the conclusion that most of them show a broad stability range with respect to the anions (e.g. Cu_{8- x} SiS_{6- x} X _{x} ; $0.51 = x \leq 1$). In contrast to Kuhs we were able to reach full substitution ($x = 1$) in the case of Cu₆AsS₅X ($X = \text{Br, I}$), Cu₇SiS₅I, and Cu₇GeS₅I. Surprisingly, the lattice constants of Cu_{7- x} AsS_{5- x} X _{x} ($X = \text{Br, I}$) are the same for the powder data in (Kuhs et al., 1979) and our single crystal measurements despite significant differences in their nominal compositions. In all other cases when the compositions are different from the values reported by Kuhs the lattice constants depict the expected trends.

Table 2. Lattice constants from powder X-ray diffraction at 298 K. All materials crystallize face centred cubic.

Compound	x^a	x^b	Lattice constants in \AA^a	Lattice constants in \AA^b
Cu _{7-x} PS _{6-x} Cl _{x}	1.00	1.00	9.687(2)	9.6828(7)
Cu _{7-x} PS _{6-x} Br _{x}	1.00	1.00	9.723(2)	9.7268(5)
Cu _{7-x} PS _{6-x} I _{x}	1.00	1.00	9.787(2)	9.7846(8)
Cu _{7-x} AsS _{6-x} Br _{x}	0.36	1.00	9.843(3)	9.8463(2)
Cu _{7-x} AsS _{6-x} I _{x}	0.95	1.00	9.892(3)	9.8989(8)
Cu _{8-x} SiS _{6-x} Br _{x}	0.60	0.18	9.876(3)	9.8356(9)
Cu _{8-x} SiS _{6-x} I _{x}	0.90	1.00	9.930(2)	9.9461(2)
		0.51		9.8967(2)
Cu _{8-x} SiSe _{6-x} I _{x}	0.83	0.56	10.346(2)	10.2852(4)
Cu _{8-x} GeS _{6-x} Br _{x}	0.70	0.25	9.953(3)	9.9398(1)
Cu _{8-x} GeS _{6-x} I _{x}	0.78	1.00	10.012(4)	10.0181(2)
Cu _{8-x} GeSe _{6-x} I _{x}	0.54	0.48	10.376(3)	10.3799(1)

a: data from (Kuhs et al., 1979)

b: calculated from single crystal data

Single crystal X-ray data collection and processing

Intensity data for all argyrodites were recorded from suitable single crystals with an ENRAF NONIUS CAD4 or a STOE IPDS I. Both diffractometers operate with MoK α radiation ($\lambda = 0.71073 \text{ \AA}$, graphite monochromator). All data were corrected for Lorentz and polarisation effects. A numerical absorption correction was applied after the optimisation of the crystal shape based on symmetry equivalent reflections (IPDS I data) or on ψ -scans (CAD4 data) using the XRED and XSHAPE routines (XRED and XSHAPE, 1999). In accordance with the results from powder X-ray diffraction and with the data from Kuhs et al. (1979) a close structural relation between the different materials becomes obvious, i.e. they all crystallize in the cubic high temperature polymorph. Therefore, the structure of Cu₆PS₅I (Kuhs, 1978b), space group $F\bar{4}3m$ (No. 216) was chosen as a model for all structure refinements. According to this model copper is localised on the 24g- and the 48h-site, the B-cation on the 4b-, the halide ion on the 4a- and the chalcogen atoms on the 16e- and 4c-site. In all cases the A-cation positions are not fully occupied in contrast to the anion- and the B-cation positions. However, the occupancy factors of the A-cation positions were refined without any restriction. In the case of a mixed occupancy of the 4a-position by Q and X the occupancy factors were restricted to full occupation. After the refinement of the atomic positions and the anisotropic displacement parameters and an extinction correction when necessary, the structure models were checked by difference Fourier analysis in order to localize the residual electron density left after the last refinement steps. Positions with significant residual electron density were added as copper positions to the structure model. Copper positions showing distances $d(\text{Cu}-\text{Cu}) < 0.4 \text{ \AA}$ and high and anisotropic displacement parameters were refined using a non-harmonic approach based on a Gram-Charlier expansion (Kuhs, 1992; Zucker and Schulz, 1982) with non-harmonic displacement parameters up to the 4th order. Only significant parameters were refined (3σ cutoff) with the

Table 3a. Parameters for the data collection of the quaternary copper silicon argyrodites. Space group $F\bar{4}3m$ (No. 216); $Z = 4$; $T = 298$ K.

Compound ^a	Cu _{7.49} SiS _{5.49} I _{0.51}	Cu ₇ SiS ₅ I	Cu _{7.82} SiS _{5.82} Br _{0.18}	Cu _{7.44} SiSe _{5.44} I _{0.56}
Refined composition	Cu _{6.80} SiS _{5.49} I _{0.51}	Cu _{6.85} SiS _{5.03} I _{0.97}	Cu _{7.88} SiS _{5.82} Br _{0.18}	Cu _{7.34} SiSe _{5.44} I _{0.56}
Idealized composition	Cu _{7.49} SiS _{5.49} I _{0.51}	Cu ₇ SiS ₅ I	Cu _{7.82} SiS _{5.82} Br _{0.18}	Cu _{7.44} SiSe _{5.44} I _{0.56}
$M_{X\text{-ray}}$ in g mole ⁻¹	744.78	760.11	729.80	1001.48
Z	4	4	4	4
Crystal size in mm ³	0.26 × 0.20 × 0.12	0.24 × 0.22 × 0.18	0.21 × 0.16 × 0.13	0.22 × 0.14 × 0.05
Crystal system	Cubic			
a in Å	9.8967(2)	9.9461(2)	9.8356(9)	10.2852(4)
V in Å ³	969.33(3)	983.92(3)	951.5(2)	1088.0(1)
$\rho_{X\text{-ray}}$ in g cm ⁻³	5.102	5.130	5.093	6.112
Absorption coefficient $\mu_{\text{MoK}\alpha}$ in mm ⁻¹	18.970	19.091	19.218	34.094
Diffractometer; Scan	IPDS I; φ	CAD4; ω	CAD4; ω	IPDS I; φ
IP distance in mm	40	—	—	40
φ -area in °; $\Delta\varphi$ in °	$-2 \leq \varphi \leq 180$; 2.0	—	—	$-2 \leq \varphi \leq 360$; 2.0
Absorption correction	Numerical; Optimized crystal shape (XRED and XSHAPE, 1999)			
Crystal description	11 faces	15 faces	15 faces	10 faces
Scan	—	ψ	ψ	—
No. images	90	—	—	181
Time/plate in min	12	—	—	8
2θ -range in °	$7.1 \leq 2\theta \leq 65.7$	$7.1 \leq 2\theta \leq 69.74$	$7.18 \leq 2\theta \leq 69.84$	$6.9 \leq 2\theta \leq 66.0$
hkl -range	$-13 \leq h \leq 14$ $-15 \leq k \leq 15$ $-15 \leq l \leq 14$	$-16 \leq h \leq 16$ $-16 \leq k \leq 0$ $-16 \leq l \leq 0$	$-15 \leq h \leq 15$ $0 \leq k \leq 15$ $0 \leq l \leq 15$	$-15 \leq h \leq 15$ $-15 \leq k \leq 15$ $-15 \leq l \leq 15$
Measured reflections	3135	1173	1141	7134
Unique reflections; $R(F^2)_{\text{int}}$	223; 0.0637	257; 0.0355	251; 0.0281	245; 0.0719
Reflections with $I > 3\sigma(I)$	208	244	233	227
No. of parameters	29	29	33	31
Refinement program	JANA98 (Petricek et al., 1998)			
R/wR ($I_{\text{obs}} > 3\sigma(I_{\text{obs}})$)	0.0275/0.0553	0.0265/0.0641	0.0221/0.0560	0.0319/0.0675
R/wR (all reflections)	0.0321/0.0562	0.0284/0.0649	0.0265/0.0577	0.0356/0.0682
GoF	2.93	1.68	2.0	2.45
Extinction coefficient	1.36(7)	0.69(4)	0.56(3)	0.77(4)
Max/min. residual electron dens. in e Å ⁻³	1.31/−0.66	0.89/−0.40	0.82/−0.63	1.29/−0.97

a: Supplementary material: Crystallographic data (excluding structure factors) have been deposited with the Fachinformationszentrum Karlsruhe as supplementary publication CSD 414363 (Cu_{7.49}SiS_{5.49}I_{0.51}), CSD 414354 (Cu₇SiS₅I), CSD 414355 (Cu_{7.82}SiS_{5.82}Br_{0.18}) and CSD 414365 (Cu_{7.44}SiSe_{5.44}I_{0.56}). Copies of available material can be obtained, free of charge, on application to Fachinformationszentrum Karlsruhe, D-76334 Leopoldshafen, Germany, (fax: 049-7247-808-666 or e-mail: crysdata@fiz-karlsruhe.de.) The list of F_o/F_c data is available from the author up to one year after the publication has appeared.

JANA98 program package (Petricek and Dusek, 1998). A detailed description of the non-harmonic approach is given elsewhere (Pfitzner, 1997; Nilges, Reiser, Hong, Gaudin and Pfitzner, 2002).

Copper positions with $d(\text{Cu}-\text{Cu}) > 0.4$ Å were refined as split positions. All crystals were checked for inversion twinning but inversion twinning was not observed in the case of the compounds under discussion. Selected crystallographic data are summarized in Table 3a to c (crystallographic data), Table 4a to b (atomic coordinates and equivalent displacement parameters), Table 5a to c (selected bond lengths and angles). The structures were visualized using the programs DIAMOND (2001) and SCIAN (Pepke, Murray, Lyons and Hwu, 1994).

For Cu_{7.44}SiSe_{5.44}I_{0.56} a slightly modified structure model was used for the description of the anion substructure. Unusual high residual electron density was observed

close to the Se2 position when the common starting model for the Type 1 argyrodites was used. Instead of a fully occupied 4c position Se2 was refined on a 16e position close to 4c. To retain the composition of Cu_{7.44}SiSe_{5.44}I_{0.56} the occupancy factor of Se2 was restricted to 0.25.

Structure description and classification

Structure description

The structures of the argyrodites under discussion can be described using three different strategies. In all strategies the mobile A-cation substructure is related to the rigid B-cation and anion substructure. So the rigid part of the structures will be discussed first.

Table 3b. Crystallographic data for the quaternary copper germanium argyrodites. Space group $F\bar{4}3m$ (No. 216); $Z = 4$; $T = 298$ K.

Compound ^a	Cu _{7.75} GeS _{5.75} Br _{0.25}	Cu ₇ GeS ₅ I	Cu _{7.52} GeSe _{5.52} I _{0.48}
Refined composition	Cu _{7.37} GeS _{5.75} Br _{0.25}	Cu _{7.00} GeS ₅ I _{0.99}	Cu _{6.78} GeSe _{5.52} I _{0.48}
Idealized composition	Cu _{7.75} GeS _{5.75} I _{0.25}	Cu ₇ GeS ₅ I	Cu _{7.52} GeSe _{5.52} I _{0.48}
$M_{X\text{-ray}}$ in g mol ⁻¹	769.39	804.62	1047.23
Z	4	4	4
Crystal size in mm ³	0.26 × 0.22 × 0.12	0.21 × 0.16 × 0.15	0.28 × 0.20 × 0.14
Crystal system	Cubic		
a in Å	9.9398(1)	10.0181(2)	10.3799(1)
V in Å ³	982.04(3)	1005.43(5)	1118.35(5)
$\rho_{X\text{-ray}}$ in g cm ⁻³	5.202	5.314	6.218
Absorption coefficient $\mu_{\text{MoK}\alpha}$ in mm ⁻¹	21.622	21.495	35.885
Diffractometer; Scan	CAD4; ω	CAD4; ω	CAD4; ω
Absorption correction	Numerical, optimized crystal shape (XRED and XSHAPE, 1999)		
Crystal description	13 faces	14 faces	12 faces
Scan	ψ	ψ	ψ
2θ -range in °	$7.1 \leq 2\theta \leq 69.78$	$7.1 \leq 2\theta \leq 69.84$	$6.8 \leq 2\theta \leq 69.32$
hkl -range	$-16 \leq h \leq 16$ $0 \leq k \leq 16$ $0 \leq l \leq 16$	$-16 \leq h \leq 16$ $-16 \leq k \leq 16$ $-16 \leq l \leq 16$	$-16 \leq h \leq 16$ $0 \leq k \leq 16$ $0 \leq l \leq 16$
Measured reflections	1173	1874	1341
Unique reflections; $R(F^2)_{\text{int}}$	257; 0.1201	265; 0.0730	290; 0.0452
Reflections with $I > 3\sigma(I)$	234	241	273
No. parameters	34	33	32
Refinement program	JANA98 (Petricek et al., 1998)		
R/wR ($I_{\text{obs}} > 3\sigma(I_{\text{obs}})$)	0.0427/0.0970	0.0299/0.0561	0.0223/0.0582
R/wR (all reflections)	0.0473/0.1010	0.0379/0.0586	0.0275/0.0619
GoF	1.46	2.24	1.19
Extinction coefficient	1.0(1)	0.299(7)	0.21(2)
Max/min. residual electron dens. in e Å ⁻³	0.93/−0.91	1.26/−1.20	0.71/−0.74

a: Supplementary material: Crystallographic data (excluding structure factors) have been deposited with the Fachinformationszentrum Karlsruhe as supplementary publication CSD 414356 (Cu_{7.75}GeS_{5.75}Br_{0.25}), CSD 414357 (Cu₇GeS₅I), CSD 414364 (Cu_{7.52}GeSe_{5.52}I_{0.48}). Copies of available material can be obtained, free of charge, on application to Fachinformationszentrum Karlsruhe, D-76334 Leopoldshafen, Germany, (fax: 049-7247-808-666 or e-mail: crysdata@fiz-karlsruhe.de.) The list of F_o/F_c data is available from the author up to one year after the publication has appeared.

The rigid anion and the B-cation substructure

One of the most frequently used strategies is the description of the structures by a closed packed arrangement of anions and cations in between the voids. Three crystallographically different positions are forming the anion substructure of the $F\bar{4}3m$ argyrodites. In dependence of the composition the $4a$ position is preferably or fully occupied by the halide ion of the quaternary argyrodite. The tetrahedral voids of the resulting face centred cubic arrangement are centred alternately by chalcogen atoms on $4c$ or $4d$ and a chalcogen tetrahedron around the remaining voids formed by atoms on $16e$ (Fig. 1). The occupation of the $4c/4d$ position depends on the configuration of the non centrosymmetric structure. In most cases $4c/4d$ is populated by chalcogen atoms but can also be partially occupied by halogen. The center of the face centred cubic cell and each center of the cell edges is occupied by the tetrahedrally coordinated B-cations.

The A-cations are localized on a large number of linear, trigonal, and tetrahedrally coordinated positions. This

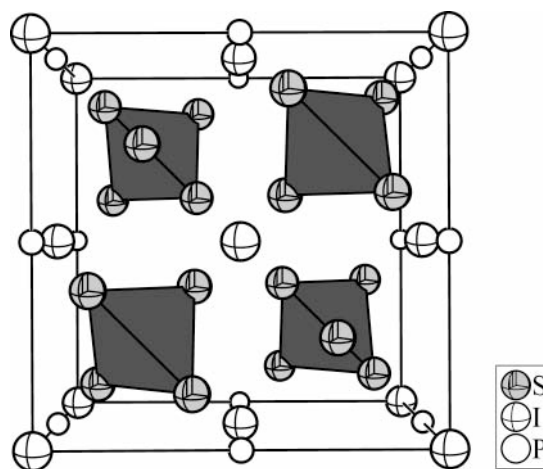
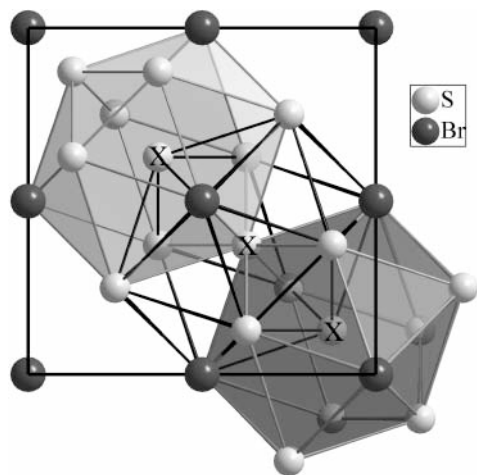


Fig. 1. B-cation and anion substructure of the cubic argyrodites illustrated for Cu₆PS₅I (space group $F\bar{4}3m$). Iodine is forming a face centred cubic arrangement. The tetrahedral voids are occupied alternately by one single chalcogen or a chalcogen tetrahedron.

Table 3c. Data collection summary for the copper arsenic and copper phosphorus argyrodites. Space group $F\bar{4}3m$ (No. 216); $Z = 4$; $T = 298$ K.

Compound ^a	Cu ₆ AsS ₅ I	Cu ₆ AsS ₅ Br	Cu ₆ PS ₅ I	Cu ₆ PS ₅ Br	Cu ₆ PS ₅ Cl
Refined composition	Cu _{6.06} AsS ₅ I	Cu _{5.95} AsS ₅ Br	Cu _{5.99} PS ₅ I	Cu _{6.04} PS ₅ Br	Cu _{6.16} PS ₅ Cl
Idealized composition	Cu ₆ AsS ₅ I	Cu ₆ AsS ₅ Br	Cu ₆ PS ₅ I	Cu ₆ PS ₅ Br	Cu ₆ PS ₅ Cl
$M_{X\text{-ray}}$ in g mol ⁻¹	743.40	696.40	699.45	652.45	608.00
Z	4				
Crystal size in mm	0.22 × 0.20 × 0.16	0.40 × 0.28 × 0.14	0.26 × 0.20 × 0.19	0.24 × 0.20 × 0.15	0.30 × 0.23 × 0.19
Crystal system	cubic				
a in Å	9.8989(8)	9.8463(2)	9.7846(8)	9.7268(5)	9.6828(7)
V in Å ³	970.0(1)	954.60(4)	936.8(1)	920.27(8)	907.8(1)
$\rho_{X\text{-ray}}$ in g cm ⁻³	5.089	4.844	4.958	4.708	4.447
Absorption coefficient $\mu_{\text{MoK}\alpha}$ in mm ⁻¹	20.491	21.773	17.883	19.190	15.346
Diffractometer; Scan	CAD4; ω	IPDS I; φ	CAD4; ω	CAD4; ω	CAD4; ω
IP distance in mm	—	45	—	—	—
φ -range in °; $\Delta\varphi$ in °	—	$-2 \leq \varphi \leq 360$; 2.0	—	—	—
Absorption correction	Numerical. Optimized crystal shape (XRED and XSHAPE, 1999)				
Crystal description	16 faces	14 faces	17 faces	18 faces	18 faces
Scan	ψ		ψ	ψ	ψ
No. of images	—	181	—	—	—
Time/image in min	—	5	—	—	—
2θ -range in °	$7.1 \leq 2\theta \leq 69.5$	$5.1 \leq 2\theta \leq 63.4$	$7.2 \leq 2\theta \leq 69.9$	$7.2 \leq 2\theta \leq 69.6$	$7.2 \leq 2\theta \leq 69.8$
hkl -range	$0 \leq h \leq 15$ $0 \leq k \leq 15$ $-15 \leq l \leq 15$	$-14 \leq h \leq 14$ $-14 \leq k \leq 14$ $-14 \leq l \leq 14$	$-15 \leq h \leq 15$ $-15 \leq k \leq 15$ $0 \leq l \leq 15$	$-15 \leq h \leq 15$ $0 \leq k \leq 15$ $0 \leq l \leq 15$	$-15 \leq h \leq 15$ $0 \leq k \leq 15$ $0 \leq l \leq 15$
Measured reflections	1169	5665	2151	1103	1081
Unique reflections; $R(F^2)_{\text{int}}$	256; 0.0425	197; 0.0639	248; 0.0414	244; 0.0330	241; 0.0619
Reflections with $I > 3\sigma(I)$	253	197	239	226	229
No. of parameters	21	20	20	20	27
Refinement program	JANA98 (Petricek et al., 1998)				
R/wR ($I_{\text{obs}} > 3\sigma(I_{\text{obs}})$)	0.0172/0.0429	0.0158/0.0297	0.0126/0.0341	0.0170/0.0463	0.0234/0.0592
R/wR (all reflections)	0.0175/0.0432	0.0158/0.0297	0.0137/0.0351	0.0193/0.0481	0.0267/0.0612
GoF	1.14	2.09	1.25	1.15	1.17
Extinction coefficient	1.18(4)	0.77(3)	0.30(2)	0.12(1)	4.6(2)
Max/min. residual electron dens. in e Å ⁻³	1.31/−0.82	0.40/−0.67	0.38/−0.35	0.22/−0.27	0.50/−0.42

a: Supplementary material: Crystallographic data (excluding structure factors) have been deposited with the Fachinformationszentrum Karlsruhe as supplementary publication CSD 414358 (Cu₆AsS₅I), CSD 414359 (Cu₆AsS₅Br), CSD 414360 (Cu₆PS₅I), CSD 414362 (Cu₆PS₅Br), and CSD 414361 (Cu₆PS₅Cl). Copies of available material can be obtained, free of charge, on application to Fachinformationszentrum Karlsruhe, D-76334 Leopoldshafen, Germany, (fax: 049-7247-808-666 or e-mail: crysdata@fiz-karlsruhe.de.) The list of F_o/F_c data is available from the author up to one year after the publication has appeared.

**Fig. 2.** Anion substructure of Cu₆PS₅Br as an example for the cubic argyrodites (space group $F\bar{4}3m$) illustrated distorted, interpenetrating icosahedra. The unit cell is drawn for clarity.

approach to describe the distribution of the A-cations is rather difficult due to the high degree of disorder.

A second known strategy to describe the rigid anion substructure is based on a polyhedron representation Kuhs (1978b), described the anion substructure of the $F\bar{4}3m$ argyrodites by interpenetrating distorted icosahedra (see Fig. 2). The centre of the icosahedron is defined by the 16e positions of the chalcogen tetrahedron. The same structural motive is known for cubic Laves phases like MgCu₂ (Ohba, Kitano and Komura, 1984). Similar to the first strategy one ends up with the same problems describing the A-cation substructure.

The mobile A-cation substructure

A somewhat different strategy has to be used for the description of the rigid substructure in order to achieve a more comprehensive structure description of the A-cation substructure.

Table 4a. Fractional atomic coordinates and equivalent displacement parameters U_{eq} in \AA^2 with e.s.d.s in parentheses for the Type 1 argyrodites. The maxima of the electron density of positions refined using a non-harmonic approach, the so-called mode positions, are marked with the suffix d . $U_{\text{eq}} = \frac{1}{2} \sum \sum U_{ij} a^i a^j a_i a_j$

	Pos.	sof	x	y	z	U_{eq}
Cu₆PS₅Br						
Cu1	24g	0.60(2)	−0.0238(1)	0.25	y	0.042(1)
Cu2	48h	0.204(8)	−0.0197(2)	0.1910(8)	y	0.0332(9)
S1	16e	1	0.3780(1)	x	x	0.0125(1)
S2	4d	1	0.75	x	x	0.0201(2)
Br	4a	1	0	x	x	0.0242(1)
P	4b	1	0	0.5	x	0.0083(2)
Cu₆PS₅I						
Cu1	24g	0.57(7)	−0.0234(2)	0.25	y	0.051(8)
Cu2	48h	0.21(4)	−0.0193(5)	0.201(2)	y	0.028(1)
S1	16e	1	0.3786(1)	x	x	0.0105(1)
S2	4d	1	0.75	x	x	0.0167(1)
I	4a	1	0	x	x	0.0154(1)
P	4b	1	0	0.5	x	0.0072(1)
Cu₆AsS₅Br						
Cu1	24g	0.65(1)	0.0248(1)	0.25	y	0.042(1)
Cu2	48h	0.171(6)	0.0190(2)	0.1909(7)	y	0.0317(8)
S1	16e	1	0.6270(1)	x	x	0.0109(1)
S2	4c	1	0.25	x	x	0.0176(1)
Br	4a	1	0	x	x	0.0285(1)
As	4b	1	0	0.5	x	0.0067(1)
Cu₆AsS₅I						
Cu1	24g	0.65(8)	−0.0242(2)	0.25	y	0.056(8)
Cu2	48h	0.18(4)	−0.0192(9)	0.200(2)	y	0.028(2)
S1	16e	1	0.3733(1)	x	x	0.0115(1)
S2	4d	1	0.75	x	x	0.0175(2)
I	4a	1	0	x	x	0.0178(1)
As	4b	1	0	0.5	x	0.0076(1)
Cu₇SiS₅I						
Cu1	24g	0.75(2)	0.0233(1)	0.25	y	0.050(1)
Cu2	48h	0.20(1)	0.001(1)	0.180(1)	y	0.085(3)
S1	16e	1	0.6230(1)	x	x	0.0123(2)
I2	4c	0.047(5)	0.25	x	x	0.0188(3)
S2	4c	0.953	0.25	x	x	0.0188
I3	4a	0.93(1)	0	x	x	0.0273(2)
S3	4a	0.07	0	x	x	0.0273
Si	4b	1	0	0.5	x	0.0076(2)
Cu2 _d	48h		0.0109	0.1925	y	
Cu₇GeS₅I						
Cu1	24g	0.77(1)	0.0246(1)	0.25	y	0.053(1)
Cu2	48h	0.197(6)	−0.011(1)	0.1762(8)	y	0.112(3)
S1	16e	1	0.6265(1)	x	x	0.0152(2)
I2	4c	0.055(6)	0.25	x	x	0.0215(4)
S2	4c	0.945	0.25	x	x	0.0215
I3	4a	0.947(9)	0	x	x	0.0279(2)
S3	4a	0.053	0	x	x	0.0279
Ge	4b	1	0	0.5	x	0.0095(1)
Cu2 _d	48h		0.0116	0.1917	y	
Cu_{7.44}SiSe_{5.44}I_{0.56}						
Cu1	24g	0.58(1)	0.0292(2)	0.25	y	0.069(2)
Cu2	48h	0.321(8)	0.0106(8)	0.1684(6)	y	0.078(2)
Se1	16e	1	0.6262(1)	x	x	0.0144(1)
Se2	16e	0.25	0.244(2)	0.256(2)	y	0.028(1)
I3	4a	0.56(2)	0	x	x	0.0298(3)
Se3	4a	0.44	0	x	x	0.0298
Si	4b	1	0	0.5	x	0.0117(3)
Cu2 _d	48h		0.0160	0.1815	y	

Table 4b. Fractional atomic coordinates and equivalent displacement paramters U_{eq} in Å² with e.s.d.s in parentheses for the argyrodites of Type 2, 3, and 4. The maxima of the electron density of positions refined using a non-harmonic approach, the so-called mode positions, are marked with the suffix *d*. $U_{ij} = \frac{1}{2} \sum \sum U_{ij} a^i a^j a_i a_j$

	Pos.	sof	x	y	z	U_{eq}
Type 2						
Cu_{7.49}SiS_{5.49}I_{0.51}						
Cu1	24g	0.617(7)	0.0244(1)	0.25	y	0.0476(5)
Cu2	48h	0.221(4)	0.0045(4)	0.1768(5)	y	0.070(1)
Cu3	16e	0.112(8)	0.1218(6)	x	x	0.113(6)
S1	16e	1	0.6233(1)	x	x	0.0086(1)
S2	4c	1	0.25	x	x	0.0165(2)
I3	4a	0.508(1)	0	x	x	0.0185(1)
S3	4a	0.492	0	x	x	0.0185
Si	4b	1	0	0.5	x	0.0063(2)
Cu2 _d	48h		0.0119	0.1911	y	
Cu₆PS₅Cl						
Cu1	24g	0.531(6)	0.0246(1)	0.25	y	0.0351(5)
Cu2	48h	0.229(4)	0.0170(3)	0.1805(3)	y	0.0403(7)
Cu3	16e	0.067(7)	0.1160(7)	x	x	0.061(4)
S1	16e	1	0.6223(1)	x	x	0.0127(1)
S2	4c	1	0.25	x	x	0.0208(2)
Cl	4a	1	0	x	x	0.0350(3)
P	4b	1	0	0.5	x	0.0082(2)
Cu2 _d	48h		0.0185	0.1847	y	
Type 3						
Cu_{7.82}SiS_{5.82}Br_{0.18}						
Cu1	24g	0.546(5)	−0.0245(1)	0.25	y	0.0442(5)
Cu2	48h	0.236(7)	−0.0345(5)	0.1679(5)	y	0.0663(9)
Cu3	48h	0.148(7)	0.035(2)	0.1543(7)	y	0.080(4)
S1	16e	1	0.3763(1)	x	x	0.0122(1)
S2	4d	1	0.75	x	x	0.0192(2)
Br3	4 _a	0.181(9)	0	x	x	0.0317(3)
S3	4a	0.819	0	x	x	0.0317
Si	4b	1	0	0.5	x	0.0080(2)
Cu2 _d	48h		−0.0206	0.1783	y	
Cu_{7.75}GeS_{5.75}Br_{0.25}						
Cu1	24g	0.52(2)	−0.0256(3)	0.25	y	0.037(1)
Cu2	48h	0.21(1)	−0.036(1)	0.175(2)	y	0.082(5)
Cu3	48h	0.15(1)	0.037(3)	0.156(1)	y	0.083(7)
S1	16e	1	0.3730(1)	x	x	0.0145(2)
S2	4d	1	0.75	x	x	0.0213(3)
Br3	4a	0.25(3)	0	x	x	0.0296(7)
S3	4a	0.75(3)	0	x	x	0.0296(7)
Ge	4b	1	0	0.5	x	0.0091(2)
Cu2 _d	48h		−0.0224	0.1849	y	
Type 4						
Cu_{7.52}GeSe_{5.52}I_{0.48}						
Cu1	24g	0.53(1)	−0.0292(3)	0.25	y	0.061(2)
Cu2	48h	0.270(6)	−0.0087(8)	0.1726(5)	y	0.068(1)
Cu3	24f	0.059(8)	0	0.200(2)	x	0.14(2)
Se1	16e	1	0.3712(1)	x	x	0.0168(1)
Se2	4d	1	0.75	x	x	0.0333(2)
I3	4a	0.48048	0	x	x	0.0306(2)
Se3	4a	0.519528	0	x	x	0.0306
Ge	4b	1	0	0.5	x	0.0114(1)
Cu2 _d	48h		−0.0169	0.1825	y	

Table 5a. Anisotropic displacement parameters U_{ij} in \AA^2 with e.s.d.s in parentheses for the Type 1 argyrodites.

	U_{11}	U_{22}	U_{33}	U_{12}	U_{13}	U_{23}
Cu₆PS₅Br						
Cu1	0.0190(4)	0.054(3)	U_{22}	0	0	0.036(3)
Cu2	0.024(1)	0.038(2)	U_{22}	0.003(1)	U_{12}	0.017(2)
S1	0.0125(2)	U_{11}	U_{11}	−0.002(1)	U_{12}	U_{12}
S2	0.0201(3)	U_{11}	U_{11}	0	0	0
Br	0.0242(2)	U_{11}	U_{11}	0	0	0
P	0.0083(3)	U_{11}	U_{11}	0	0	0
Cu₆PS₅I						
Cu1	0.0169(4)	0.07(2)	U_{22}	0	0	0.05(2)
Cu2	0.0209(9)	0.031(2)	U_{22}	0.003(1)	U_{12}	0.013(3)
S1	0.0105(1)	U_{11}	U_{11}	−0.002(1)	U_{12}	U_{12}
S2	0.0167(2)	U_{11}	U_{11}	0	0	0
I	0.0154(1)	U_{11}	U_{11}	0	0	0
P	0.0072(2)	U_{11}	U_{11}	0	0	0
Cu₆AsS₅Br						
Cu1	0.0172(3)	0.055(2)	U_{22}	0	0	0.038(2)
Cu2	0.0243(9)	0.035(1)	U_{22}	−0.004(1)	U_{12}	0.014(2)
S1	0.0109(1)	U_{11}	U_{11}	−0.002(1)	U_{12}	U_{12}
S2	0.0176(2)	U_{11}	U_{11}	0	0	0
Br	0.0285(1)	U_{11}	U_{11}	0	0	0
As	0.0067(1)	U_{11}	U_{11}	0	0	0
Cu₆AsS₅I						
Cu1	0.0184(6)	0.07(2)	U_{22}	0	0	0.06(2)
Cu2	0.023(1)	0.030(3)	U_{22}	0.003(1)	U_{12}	0.010(3)
S1	0.0115(2)	U_{11}	U_{11}	−0.002(1)	U_{12}	U_{12}
S2	0.0175(3)	U_{11}	U_{11}	0	0	0
I	0.0178(2)	U_{11}	U_{11}	0	0	0
As	0.0076(2)	U_{11}	U_{11}	0	0	0
Cu₇SiS₅I						
Cu1	0.0225(5)	0.064(3)	U_{22}	0	0	0.040(3)
Cu2	0.115(6)	0.070(4)	U_{22}	−0.005(3)	U_{12}	0.015(3)
S1	0.0123(3)	U_{11}	U_{11}	−0.002(1)	U_{12}	U_{12}
I2/S2	0.0188(5)	U_{11}	U_{11}	0	0	0
I3/S3	0.0273(3)	U_{11}	U_{11}	0	0	0
Si	0.0076(4)	U_{11}	U_{11}	0	0	0
Cu₇GeS₅I						
Cu1	0.0258(6)	0.067(2)	U_{22}	0	0	0.037(2)
Cu2	0.209(7)	0.063(3)	U_{22}	0.013(3)	U_{12}	0.017(3)
S1	0.0152(3)	U_{11}	U_{11}	−0.003(1)	U_{12}	U_{12}
I2/S2	0.0215(6)	U_{11}	U_{11}	0	0	0
I3/S3	0.0279(3)	U_{11}	U_{11}	0	0	0
Ge	0.0095(2)	U_{11}	U_{11}	0	0	0
Cu_{7.44}SiSe_{5.44}I_{0.56}						
Cu1	0.027(1)	0.090(5)	U_{22}	0	0	0.063(5)
Cu2	0.093(5)	0.070(2)	U_{22}	0.002(2)	U_{12}	−0.002(3)
Se1	0.0144(2)	U_{11}	U_{11}	−0.003(1)	U_{12}	U_{12}
Se2	0.028(2)	U_{11}	U_{11}	−0.010(4)	U_{12}	U_{12}
I3/Se3	0.0298(5)	U_{11}	U_{11}	0	0	0
Si	0.0117(6)	U_{11}	U_{11}	0	0	0

Instead of a description by interpenetrating icosahedra one can also use a set of face sharing Frank-Kasper polyhedra with a coordination number of 16, so called Friauf polyhedra (see Fig. 3). Around the 4c/4d position these

polyhedra are spread up by anions on the 16e and 4a positions. Four of these Friauf polyhedra are arranged around the B-cation position forming a tetrahedral void centred by 4b (Fig. 4). A Friauf polyhedron itself can be divided into

Table 5b. Anisotropic displacement parameters U_{ij} in \AA^2 with e.s.d.s in parentheses for the argyrodites of Type 2, 3, and 4.

	U_{11}	U_{22}	U_{33}	U_{12}	U_{13}	U_{23}
Type 2						
Cu_{7.49}SiS_{5.49}I_{0.51}						
Cu1	0.0184(5)	0.062(1)	U_{22}	0	0	0.042(1)
Cu2	0.074(2)	0.068(2)	U_{22}	0.020(1)	U_{12}	0.045(2)
Cu3	0.11(1)	U_{11}	U_{11}	−0.048(5)	U_{12}	U_{12}
S1	0.0086(2)	U_{11}	U_{11}	−0.003(1)	U_{12}	U_{12}
S2	0.0165(3)	U_{11}	U_{11}	0	0	0
I3/S3	0.0185(2)	U_{11}	U_{11}	0	0	0
Si	0.0063(3)	U_{11}	U_{11}	0	0	0
Cu₆PS₅Cl						
Cu1	0.0195(5)	0.043(1)	U_{22}	0	0	0.024(1)
Cu2	0.033(1)	0.044(1)	U_{22}	−0.001(1)	U_{12}	0.021(1)
Cu3	0.061(7)	U_{11}	U_{11}	−0.025(4)	U_{12}	U_{12}
S1	0.0127(2)	U_{11}	U_{11}	−0.003(1)	U_{12}	U_{12}
S2	0.0208(4)	U_{11}	U_{11}	0	0	0
Cl	0.0350(6)	U_{11}	U_{11}	0	0	0
P	0.0082(3)	U_{11}	U_{11}	0	0	0
Type 3						
Cu_{7.82}SiS_{5.82}Br_{0.18}						
Cu1	0.0210(4)	0.056(1)	U_{22}	0	0	0.035(1)
Cu2	0.074(2)	0.063(1)	U_{22}	0.033(2)	U_{12}	0.023(2)
Cu3	0.13(1)	0.056(2)	U_{22}	−0.030(3)	U_{12}	−0.014(2)
S1	0.0122(2)	U_{11}	U_{11}	−0.003(1)	U_{12}	U_{12}
S2	0.0192(3)	U_{11}	U_{11}	0	0	0
Br3/S3	0.0317(5)	U_{11}	U_{11}	0	0	0
Si	0.0080(3)	U_{11}	U_{11}	0	0	0
Cu_{7.75}GeS_{5.75}Br_{0.25}						
Cu1	0.020(1)	0.046(2)	U_{22}	0	0	0.022(3)
Cu2	0.067(7)	0.090(9)	U_{22}	0.040(5)	U_{12}	0.06(1)
Cu3	0.17(2)	0.041(3)	U_{22}	−0.037(6)	U_{12}	−0.004(4)
S1	0.0145(4)	U_{11}	U_{11}	−0.003(1)	U_{12}	U_{12}
S2	0.0213(6)	U_{11}	U_{11}	0	0	0
Br3/S3	0.030(1)	U_{11}	U_{11}	0	0	0
Ge	0.0091(3)	U_{11}	U_{11}	0	0	0
Type 4						
Cu_{7.52}GeSe_{5.52}I_{0.48}						
Cu1	0.029(1)	0.076(3)	U_{22}	0	U_{12}	0.049(3)
Cu2	0.082(3)	0.062(2)	U_{22}	−0.016(2)	U_{12}	0.019(2)
Cu3	0.21(5)	0.018(9)	U_{11}	0	−0.12(5)	U_{12}
Se1	0.0168(2)	U_{11}	U_{11}	−0.003(1)	U_{12}	U_{12}
Se2	0.0333(4)	U_{11}	U_{11}	0	0	0
I3	0.0306(3)	U_{11}	U_{11}	0	0	0
Se3	0.0306(3)	U_{11}	U_{11}	0	0	0
Ge	0.0114(2)	U_{11}	U_{11}	0	0	0

sets of trigonal biramids as shown in Fig. 5. These biramids represent the smallest section of the rigid substructure necessary to analyse the distribution of the mobile A-cations in the argyrodites. The linear, three- and four-coordinated copper positions present in the argyrodites can be all localized relative to only one of the defined bipyramids (see Fig. 6a and 6b). The argyrodites under discussion can be separated into four different types according to the copper distribution and copper content. In general, the num-

ber of copper positions increases with an increasing copper content as expected. The copper distribution of the group 15 argyrodites (according the B-cation), showing the lowest copper content per formula unit, can be described by a trigonally coordinated 24g and a fourfold coordinated 48a position. Those argyrodites and some of the group 14 ones with a high iodide content and therefore small copper contents relative to the maximum of 8 copper atoms per formula unit (e.g. Cu₇SiS₅I or

Table 6a. Selected interatomic distances in Å and angles in ° with e.s.d.s in parentheses for the Type 1 argyrodites (*B*-cation: group 15).

Type 1			
Cu₆PS₅Br			
Cu1–Cu1	3.111(1)	S1–Cu1–S1	102.30(5)
Cu1–Cu2	0.812(8)	S1–Cu1–S2	128.85(2)
Cu1–S1	2.2612(8)		
Cu1–S2	2.200(1)		
Cu2–Cu2	1.62(1)	S1–Cu2–S1	95.5(2)
Cu2–S1	2.379(7)	S1–Cu2–S2	115.4(3)
Cu2–S2	2.382(3)	S1–Cu2–Br	107.3(3)
Cu2–Br	2.635(8)	S2–Cu2–Br	114.1(2)
P–S1	2.0551(5)	S1–P–S1	109.47(2)
Cu₆PS₅I			
Cu1–Cu1	3.136(2)	S1–Cu1–S1	102.98(7)
Cu1–Cu2	0.68(1)	S1–Cu1–S2	128.51(3)
Cu1–S1	2.274(1)		
Cu1–S2	2.218(2)		
Cu2–Cu2	1.36(2)	S1–Cu2–S1	98.4(3)
Cu2–S1	2.35(1)	S1–Cu2–S2	118.5(6)
Cu2–S2	2.358(7)	S1–Cu2–I	104.5(5)
Cu2–I	2.78(1)	S2–Cu2–I	110.7(4)
P–S1	2.0571(4)	S1–P–S1	109.47(2)
Cu₆AsS₅Br			
Cu1–Cu1	3.1365(7)	S1–Cu1–S1	97.83(3)
Cu1–Cu2	0.825(7)	S1–Cu1–S2	131.08(2)
Cu1–S1	2.2731(6)		
Cu1–S2	2.2178(7)		
Cu2–Cu2	1.65(1)	S1–Cu2–S1	92.0(1)
Cu2–S1	2.383(6)	S1–Cu2–S2	116.7(3)
Cu2–S2	2.419(3)	S1–Cu2–Br	107.6(2)
Cu2–Br	2.665(7)	S2–Cu2–Br	113.9(2)
As–S1	2.1651(3)	S1–As–S1	109.47(1)
Cu₆AsS₅I			
Cu1–Cu1	3.161(2)	S1–Cu1–S1	98.27(7)
Cu1–Cu2	0.70(2)	S1–Cu1–S2	130.87(4)
Cu1–S1	2.283(1)		
Cu1–S2	2.236(2)		
Cu2–Cu2	1.40(2)	S1–Cu2–S1	94.2(4)
Cu2–S1	2.36(1)	S1–Cu2–S2	119.9(7)
Cu2–S2	2.39(1)	S1–Cu2–I	104.7(5)
Cu2–I	2.81(2)	S2–Cu2–I	110.9(5)
As–S1	2.1723(5)	S1–As–S1	109.47(2)

Cu_{7.44}SiSi_{5.44}I_{0.56}) are representing the Type 1 structure argyrodites.

Besides the type 1 argyrodites a linear coordinated 16e position was observed for the Type 2 argyrodites. Cu₆PS₅Cl and Cu_{7.49}SiSi_{5.49}I_{0.51} are representing the type 2 argyrodites. Surprisingly, Cu₆PS₅Cl belongs to the Type 2 argyrodites in contrast to the heavier homologues. This finding fits well to the unexpected trend of the ionic conductivities of Cu₆PS₅X (X = Cl, Br, I) reported by Kuhs

Table 6b. Selected interatomic distances in Å and angles in ° with e.s.d.s in parentheses for the Type 1 argyrodites (*B*-cation: group 14). The maxima of electron density, the so-called mode positions (suffix *d*), were used for distance and angle calculations in case of a non-harmonic development of the displacement parameters.

Type 1			
Cu₇SiS₅I			
Cu1–Cu1	3.189(1)		
Cu1–Cu _d	0.8182(2)		
Cu1–S1	2.304(1)	S1–Cu1–S1	101.63(5)
Cu1–I2/S2	2.255(1)	S1–Cu1–I2/S2	129.18(3)
Cu _d –Cu _d	1.6176	S1–Cu _d –S1	97.78(2)
Cu _d –S1	2.3702(6)	S1–Cu _d –I2/S2	114.98(1)
Cu _d –I2/S2	2.5119	S1–Cu _d –I3/S3	108.57(1)
Cu _d –I3/S3	2.7099	I2/S2–Cu _d –I3/S3	111.076
Si–S1	2.1197(6)	S1–Si–S1	109.47(2)
Cu₇GeS₅I			
Cu1–Cu1	3.193(1)	S1–Cu1–S1	98.25(5)
Cu1–Cu _d	0.8362(2)	S1–Cu1–I2/S2	130.87(3)
Cu1–S1	2.314(1)		
Cu1–I2/S2	2.258(1)		
Cu _d –Cu _d	1.652	S1–Cu _d –S1	94.71(2)
Cu _d –S1	2.3786(7)	S1–Cu _d –I2/S2	115.86(2)
Cu _d –I2/S2	2.5271	S1–Cu _d –I3/S3	108.79(2)
Cu _d –I3/S3	2.7184	I2/S2–Cu _d –I3/S3	111.528
Ge–S1	2.1951(7)	S1–Ge–S1	109.47(3)
Cu_{7.44}SiSe_{5.44}I_{0.56}			
Cu1–Se1	2.408(2)	Se1–Cu1–Se1	96.80(9)
Cu1–Se2	2.21(2)	Se1–Cu1–Se2	131.6(4)
Cu1–Se2	2.33(2)	Se1–Cu1–Se2	129.6(4)
Cu1–Cu _d	1.0056(3)	Se1–Cu1–Se2	133.6(4)
Cu _d –Se1	2.5247(8)	Se1–Cu _d –Se1	90.99(3)
Cu _d –Se2	2.58(2)	Se1–Cu _d –Se2	111.2(3)
Cu _d –Se2	2.66(2)	Se1–Cu _d –Se2	111.5(3)
Cu _d –I3/Se3	2.6451	Se1–Cu _d –Se2	113.4(4)
Cu _d –Cu _d	1.9927	Se1–Cu _d –Se2	114.3(3)
		Se1–Cu _d –I3/Se3	110.97(2)
		Se2–Cu _d –I3/Se3	118.2(3)
		Se2–Cu _d –I3/Se3	115.6(3)
		Se2–Cu _d –I3/Se3	114.8(4)
Si–Se1	2.2484(8)	Se1–Si–Se1	109.47(3)

el al. (1979). Kuhs found the highest ion conductivity for Cu₆PS₅Cl followed by Cu₆PS₅I and Cu₆PS₅Br. No proper reason was given for this finding. A significant higher copper mobility can be expected for Cu₆PS₅Cl than for the other two homologues based on the differences in copper coordination and distribution.

Joint probability density function (jpdf) analysis

After a non-harmonic refinement of the A-cation substructure a joint probability density function analysis was applied to identify possible diffusion pathways for the mobile ions and to highlight the differences in copper

Table 6c. Selected interatomic distances in Å and angles in ° with e.s.d.s in parentheses for the Type 2 argyrodites. The maxima of electron density, the so-called mode positions (suffix *d*) were used for distance and angle calculations in case of a non-harmonic development of displacement parameters.**Type 2****Cu_{7.49}SiS_{5.49}I_{0.51}**

Cu1–Cu1	3.157(1)	S1–Cu1–S1	100.97(6)
–Cu3	2.036(6)	S1–Cu1–S2	129.51(3)
–S1	2.298(1)	S1–Cu1–S1	100.97(6)
–S2	2.233(1)	S1–Cu1–S2	129.51(3)
–Cu2 _d	0.8336(2)		
Cu2 _d –Cu2 _d	1.649	S1–Cu2 _d –S1	96.88(2)
–Cu3	1.457(6)	S1–Cu2 _d –S2	114.73(1)
–S1	2.3693(5)	S1–Cu2 _d –I3/S3	108.83(1)
–S2	2.496	S2–Cu2 _d –I3/S3	111.803
–I3/S3	2.677		
Cu3–S2	2.197(6)	S2–Cu3–I3/S3	180
–I3/S3	2.089(6)		

Si–S1

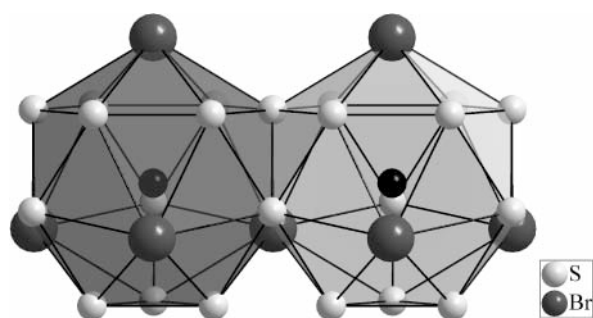
2.1141(5)	S1–Si–S1	109.47(2)
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Cu₆PS₅Cl

Cu1–Cu1	3.087(1)	S1–Cu1–S1	101.78(5)
Cu1–Cu2 _d	0.8961(1)	S1–Cu1–S2	129.11(3)
Cu1–Cu3	2.037(6)		
Cu1–S1	2.2540(9)		
Cu1–S2	2.183(1)		
Cu2 _d –Cu2 _d	1.788	S1–Cu2 _d –S1	94.02(2)
Cu2 _d –S1	2.3909(6)	S1–Cu2 _d –S2	113.01(1)
Cu2 _d –S2	2.4133	S1–Cu2 _d –Cl	109.44(1)
Cu2 _d –Cl	2.536	S2–Cu2 _d –Cl	115.799
Cu3–Cu3	3.178(9)	S2–Cu3–Cl	180
Cu3–S2	2.247(6)		
Cu3–Cl	1.946(6)		
P–S1	2.0507(6)	S1–P–S1	109.47(2)

coordination for the argyrodites. The Type 1 and Type 2 argyrodites can be differentiated into subgroups after the jpdf analysis.

Type 1 argyrodites can be divided into two subgroups related to the PSE group number of the *B*-cation and the resulting copper content of the argyrodites. The higher

**Fig. 3.** Face sharing Frank-Kasper polyhedra around a 4c/4d position (small black spheres) in cubic argyrodites illustrated for Cu₆PS₅Br. The polyhedra are connected via S₂X faces.**Table 6d.** Selected interatomic distances in Å and angles in ° with e.s.d.s in parentheses for the Type 3 and Type 4 argyrodites. The maxima of electron density, the so-called mode positions (suffix *d*), were used for distance and angle calculations in case of a non-harmonic development of displacement parameters.**Type 3****Cu_{7.82}SiS_{5.82}Br_{0.18}**

Cu1–Cu1	3.1360(9)	S1–Cu1–S1	100.62(4)
–Cu2 _d	0.9981	S1–Cu1–S2	129.69(2)
–Cu3	1.46(1)		
–S1	2.2831(8)		
–S2	2.2175(9)		
Cu2 _d –Cu2 _d	1.9946	S1–Cu2 _d –S1	90.73(2)
–Cu3	0.64(2)	S1–Cu2 _d –S2	111.25(1)
–S1	2.4689(5)	S1–Cu2 _d –Br3/S3	110.84(1)
–S2	2.4669	S2–Cu2 _d –Br3/S3	118.517
–Br3/S3	2.4884		
–Cu3	1.66(2)	S1–Cu3–S1	95.7(4)
Cu3–S1	2.37(1)	S1–Cu3–S2	95.2(4)
–S2	3.11(2)	S1–Cu3–Br3/S3	127.8(4)
–Br3/S3	2.174(7)	S2–Cu3–Br3/S3	106.2(7)

Si–S1

2.1072(5)	S1–Si–S1	109.47(2)
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Cu_{7.75}GeS_{5.75}Br_{0.25}

Cu1–Cu1	3.155(3)	S1–Cu1–S1	97.5(1)
Cu1–Cu2 _d	0.9157(1)	S1–Cu1–S2	131.26(5)
Cu1–Cu3	1.46(2)		
Cu1–S1	2.300(2)		
Cu1–S2	2.231(3)		
Cu2 _d –Cu3	0.72(3)	S1–Cu2 _d –S1	89.49(3)
Cu2 _d –S1	2.456(1)	S1–Cu2 _d –S2	114.89(2)
Cu2 _d –S2	2.4404	S1–Cu2 _d –Br3/S3	108.64(2)
Cu2 _d –Br3/S3	2.6087	S2–Cu2 _d –Br3/S3	116.92
Cu3–Cu3	1.67(3)	S1–Cu3–S1	94.4(7)
Cu3–S1	2.36(2)	S1–Cu3–S2	96.2(6)
Cu3–S2	3.14(3)	S1–Cu3–Br3/S3	128.1(6)
Cu3–Br3/S3	2.22(1)	S2–Cu3–Br3/S3	105(1)
Ge–S1	2.187(1)	S1–Ge–S1	109.47(4)

Type 4**Cu_{7.52}GeSe_{5.52}I_{0.48}**

Cu1–Cu2 _d	0.9990(3)	Se1–Cu1–Se1	94.66(9)
Cu1–Cu3	2.663(4)	Se1–Cu1–Se2	132.67(5)
Cu1–Se1	2.420(2)		
Cu1–Se2	2.292(3)		
Cu2 _d –Cu2 _d	1.9817	Se1–Cu2 _d –Se1	89.07(1)
Cu2 _d –Cu3	1.911(2)	Se1–Cu2 _d –Se2	113.81(1)
Cu2 _d –Se1	2.5366(5)	Se1–Cu2 _d –I3/Se3	110.54(1)
Cu2 _d –Se2	2.6146	Se2–Cu2 _d –I3/Se3	116.017
Cu2 _d –I3/Se3	2.6847		
Cu3–Cu3	2.94(2)	Se1–Cu3–Se1	93.7(7)
Cu3–Se1	2.59(1)	Se1–Cu3–I3/Se3	133.1(3)
Cu3–I3/Se3	2.08(2)		
Ge–Se1	2.3158(5)	Se1–Ge–Se1	109.47(2)

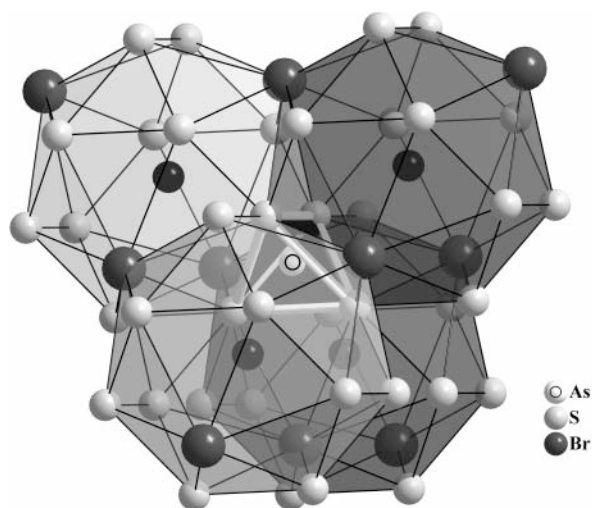


Fig. 4. Coordination of the $4b$ position (B -cation) by four Friauf polyhedra illustrated for $\text{Cu}_6\text{AsS}_5\text{Br}$.

copper content of the group 14 argyrodites causes an increasing non harmonicity of the displacement parameters and an increased tendency to occupy $[3 + 1]$ coordinated positions (see Fig. 6a) compared to the group 15 members.

Copper in $\text{Cu}_{7.49}\text{SiS}_{5.49}\text{I}_{0.51}$ (Type 2 group) tends to occupy tetrahedrally, trigonally and linearly coordinated positions within the above mentioned double tetrahedra.

Three diffusion pathways can be estimated for all four types from the shape of the corresponding jpdf. In Fig. 7 pathway 1 to 3 is illustrated by the two examples $\text{Cu}_{7.49}\text{SiS}_{5.49}\text{I}_{0.51}$ (Type 2) and $\text{Cu}_{7.52}\text{GeSe}_{5.52}\text{I}_{0.48}$ (Type 4).

Pathway 1 heading through a double tetrahedron face spread up by two $16e$ and the $4a$ position is the most favourable pathway of the Type 1 argyrodites, at least for the group 14 members. No significant preference can be observed for the group 15 members.

Type 2 argyrodites are supposed to be dominated by a copper diffusion along pathway 1 ($\text{Cu}_{7.49}\text{SiS}_{5.49}\text{I}_{0.51}$) or pathway 2 ($\text{Cu}_6\text{PS}_5\text{Cl}$).

No significant preference of pathway 1 or pathway 2 can be observed for Type 3 argyrodites.

A third pathway was found for the Type 4 argyrodite $\text{Cu}_{7.52}\text{GeSe}_{5.52}\text{I}_{0.48}$. Pathway 3 heading through the face of

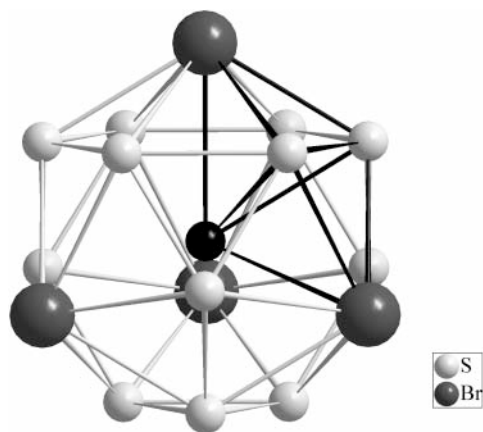


Fig. 5. Friauf polyhedra around $4c/4d$ (black sphere) illustrated for $\text{Cu}_6\text{AsS}_5\text{Br}$. Each Friauf polyhedron can be separated into 12 double tetrahedra.

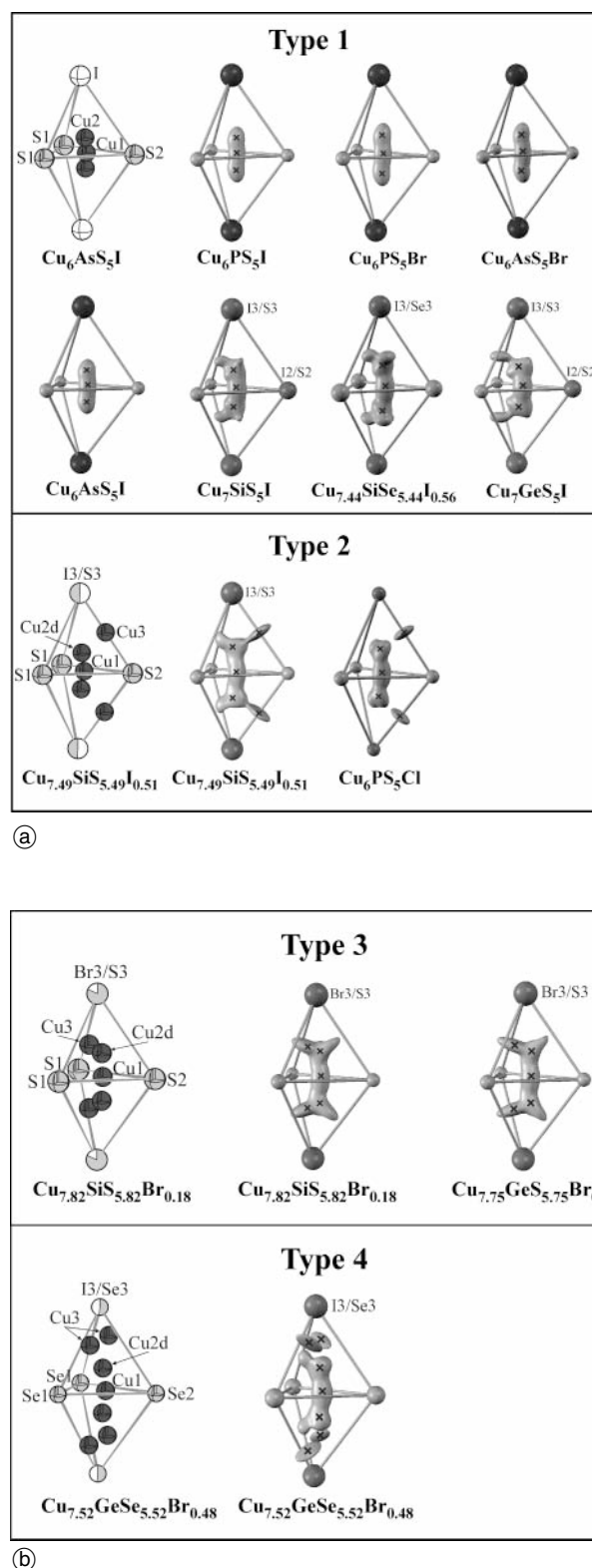


Fig. 6. (a) A-cation substructure of Type 1 and Type 2 copper argyrodites. Type 1: trigonal coordinated Cu1 on $24g$ and tetrahedrally coordinated Cu2 on $48h$. Type 2: One additional two-coordinate Cu3 on $16e$. Jpdf plots of the respective copper distribution illustrate the difference in copper coordination for the different argyrodites. Refined copper positions are marked by an x . (b) A-cation substructure of the Type 3 and Type 4 copper argyrodites. Type 3: One additional $[3 + 1]$ coordinated Cu3 besides the Type 1 positions Cu1 and Cu2 on $48h$. Type 4: One additional $[3 + 1]$ coordinated Cu3 besides the Type 1 positions Cu1 and Cu2 on $24f$. Jpdf plots of the respective copper distribution illustrate the difference in copper coordination for the different argyrodites. Refined copper positions are marked.

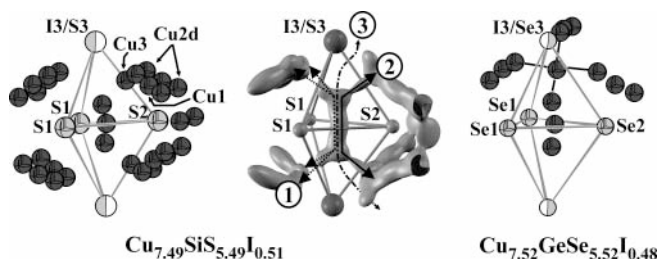


Fig. 7. Three copper diffusion pathways realized for the Type 1–4 argyrodites estimated from the shape of the jpdf. Examples are $\text{Cu}_{7.49}\text{SiS}_{5.49}\text{I}_{0.51}$ and $\text{Cu}_{7.52}\text{GeSe}_{5.52}\text{I}_{0.48}$.

a double tetrahedron which is spread up by a $16e$, $4d$ and a $4a$ position completes the set of different pathways realized by the copper argyrodites.

One particle potential (opp) analysis

In order to identify the favourite diffusion pathways and to classify the present argyrodites in terms of their potential ionic conductivity we performed one particle potential (opp) analysis along each pathway. Opps can be derived from the related jpdfs (Kuks, 1992; Bachmann and Schulz, 1984). Due to the fact that most of the copper positions are far away from full occupancy we will only give qualitative data for the opps.

In good agreement with the copper distribution derived from jpdf analysis, the highest opps of all argyrodites were observed for the group 15 members of the Type 1 argyrodites. Values between 0.6 eV and 1.3 eV for pathway 1 and pathway 2 are well above 0.3 eV. The latter activation energy is the maximum value that should be observed for good or “super” ionic conductors according to Agrawal and Gupta (1999). A higher copper content per formula unit for the group 14 members of the Type 1 argyrodites results in significant smaller opps (0.1–0.2 eV), well below the value of 0.3 eV. The maximum copper distance $d_{\text{max}}(\text{Cu}–\text{Cu})$ along a pathway is almost the same for the two pathways. For instance the distances vary between 2.36 Å and 2.53 Å (group 15 members) and between 2.41 Å and 2.55 Å (group 14 members) for pathway 1. The same narrow distance distribution is observed for pathway 2. Obviously the copper content does not have a significant influence on $d_{\text{max}}(\text{Cu}–\text{Cu})$ and therefore the maximum jump distance can not be a decisive factor for the change of the opp. Other factors influencing the occupancy of the copper positions and the coordination of copper along the diffusion pathway obviously play an important role and have to be taken into account.

The Type 2 and Type 4 argyrodites show comparable opps than the Type 1 (group 14) argyrodites. Slightly smaller opps (<0.1 eV) were observed for the Type 3 argyrodites. According to the results from opp analyses a copper diffusion seems to be possible for all copper argyrodites and the argyrodites can be ranked in terms of increasing copper mobility:

$$\text{Type 1 (group 15)} < \text{Type 1 (group 14)} \\ \cong \text{Type 2} \cong \text{Type 4} < \text{Type 3} \quad (1)$$

Type 3 argyrodites therefore seem to be the most promising candidates for high ionic conductivity.

Table 7. Total conductivities of quaternary copper argyrodites.

Compound	Conductivity ($\Omega^{-1} \text{ cm}^{-1}$)	Type	Literature
$\text{Cu}_6\text{PS}_5\text{Br}$	$1 \cdot 10^{-5}/1.2 \cdot 10^{-5}$	1 (group 15)	Kuhs et al. (1979)/ Studeniyak et al. 1997
$\text{Cu}_6\text{PS}_5\text{I}$	$5 \cdot 10^{-5}/1.3 \cdot 10^{-3}$	1 (group 15)	Kuhs et al. (1979)/ Studeniyak et al. (1997)
$\text{Cu}_6\text{PS}_5\text{Cl}$	$8 \cdot 10^{-4}/4.3 \cdot 10^{-2}$	2	Kuhs et al. (1979)/ Studeniyak et al. (1997)
$\text{Cu}_7\text{GeS}_5\text{I}$	$5.6 \cdot 10^{-3}$	1 (group 14)	Studeniyak et al. (2002)

Ionic conductivity was observed at least for some of the argyrodites under discussion, e.g. for $\text{Cu}_6\text{PS}_5\text{X}$ ($\text{X} = \text{Cl}, \text{Br}, \text{I}$) and $\text{Cu}_7\text{GeS}_5\text{I}$ (Kuhs et al., 1979; Studeniyak et al., 1997 and 2002). The predicted trend of equation (1) can be directly correlated with the measured conductivity reported by Kuhs et al. (1979), and Studeniyak et al. (1997, and 2002). Estimated conductivities at 300 K are summarized in Table 7.

Conclusion

The crystal structures of the high temperature modifications of 12 copper argyrodites were discussed with the focus on the distribution of the mobile copper ions. The argyrodites are classified into four different types according to the differences concerning the copper coordination. A new and illustrative structure description using centred, face sharing Friauf polyhedra which are separated into sets of double tetrahedra was developed to discuss the complex copper distribution of the argyrodites. Physical properties and unexpected trends of the ionic conductivities can be understood in terms of this new classification. A combined analysis of joint probability density functions and one particle potentials results in a prediction of potential ionic conductors.

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